

Silicon Carbide Schottky diode - Bare die

Rev.01 - 26 October 2021

Product data sheet

1. General description

Silicon Carbide Schottky diode (Bare Die).

2. Features and benefits

- Extremely fast reverse recovery time
- Low figure of merit $(Q_r * V_F)$
- Highly stable switching performance
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Quick reference data

Table 1. Quick reference data

	alck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{RRM}^{*}	repetitive peak reverse voltage			-	-	1200	V
I _{F(AV)} **	average forward current	δ = 0.5; square-wave pulse		-	-	10	А
Static ch	aracteristics						
V _F **	forward voltage	I _F = 10 A; T _j = 25 °C		-	1.42	1.65	V
		I _F = 10 A; T _j = 150 °C		-	1.88	2.3	V
Dynamic characteristics							
Q,**	recovered charge	I_{F} = 10 A; V_{R} = 400 V; d I_{F}/dt = 500 A/µs; T_{j} = 25 °C		-	25	-	nC

4. Ordering information

Table 2. Ordering information							
Type number	Orderable part number	Name	Description	Version			
WB10SC120AL	WB10SC120ALZ	Wafer	Bare die on wafer	Die			

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5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM} *	repetitive peak reverse voltage		-	1200	V
V _{RWM} *	crest working reverse voltage		-	1200	V
V _R *	reverse voltage	DC	-	1200	V
I _{F(AV)} **	average forward current	δ = 0.5; square-wave pulse	-	10	А
I _{FRM} **	repetitive peak forward current	δ = 0.5; $t_{\rm p}$ = 25 $\mu s;$ square-wave pulse	-	20	A
I _{FSM} **	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	72	А
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	-	850	A
T _{stg} **	storage temperature		-55	175	°C
T _j **	junction temperature		-	175	°C

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6. Characteristics

Table 4. C	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _F *	forward voltage	I _F = 10 A; T _j = 25 °C	-	1.42	1.65	V
V _F **	forward voltage	I _F = 10 A; T _j = 150 °C	-	1.88	2.3	V
l _R *	reverse current	V _R = 1200 V; T _j = 25 °C	-	3	110	μA
l _R **	reverse current	V _R = 1200 V; T _j = 150 °C	-	60	-	μA
Dynamic	characteristics					_
Q,**	recovered charge	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	-	25	-	nC
C_{d}**	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	490	-	pF
		f = 1 MHz; V _R = 400 V; T _j = 25 °C	-	48	-	pF
		f = 1 MHz; V _R = 800 V; T _j = 25 °C	-	36	-	pF
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Notes:

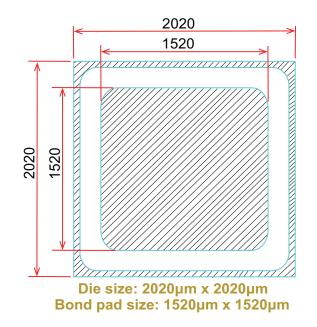
(1) * mean that parameter are 100% test at $T_{\mbox{\scriptsize amb}}$ = 25°C

(2) ** means that the guaranteed ratings and parameter limits will depend on the assembled structure. When correctly assembled with suitable die bonding and wire bonding, the device will have ratings and characteristics guaranteed in this data sheet, similar to the assembled devices like WNSC2D101200W.

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MECHANICAL SPECIFICATIONS		
Chip size	2.02 x 2.02	mm²
Anode pad size	1.52 x 1.52	mm ²
Scribe line width	80	μm
Area total / active	4.08 / 2.31	mm ²
Thickness	165	μm
Wafer size	100	mm
Max possible chips per wafer	1740	pcs
Passivation	Polyimide	
Front metal	AICu (4)	μm
Back metal	Ti Ni Ag (0.2/0.3/2.0)	μm

CHIP LAYOUT



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7. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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